Octal 3-State Noninverting Buffer/Line Driver/ Line Receiver with LSTTL-Compatible Inputs High-Performance Silicon-Gate CMOS

The MC54/74HCT241A is identical in pinout to the LS241. This device may be used as a level converter for interfacing TTL or NMOS outputs to High–Speed CMOS inputs. The HCT241A is an octal noninverting buffer/line driver/line receiver designed to be used with 3–state memory address drivers, clock drivers, and other bus–oriented systems. The device has non–inverted outputs and two output enables. Enable A is active–low and Enable B is active–high.

The HCT241A is similar in function to the HCT244. See also HCT240.

- Output Drive Capability: 15 LSTTL Loads
- TTL/NMOS-Compatible Input Levels
- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 4.5 to 5.5 V
- Low Input Current: 1 μA
- In Compliance with the Requirements Defined by JEDEC Standard No. 7A
- Chip Complexity: 118 FETs or 29.5 Equivalent Gates



MC54/74HCT241A J SUFFIX CERAMIC PACKAGE CASE 732–03 N SUFFIX



PLASTIC PACKAGE CASE 738–03 DW SUFFIX

SOIC PACKAGE

CASE 751D-04

ORDERING INFORMATION

MC54HCTXXXAJ MC74HCTXXXAN MC74HCTXXXADW Ceramic Plastic SOIC

PIN ASSIGNMENT					
ENABLE A	1●	20	□ v _{cc}		
A1 [2	19	ENABLE B		
YB4 [3	18] YA1		
A2 [4	17] B4		
үвз [5	16] YA2		
A3 [6	15] B3		
YB2 [7	14] YA3		
A4 [8	13] B2		
YB1 [9	12] YA4		
GND [10	11] B1		

Inpu	ts	Output
Enable A	Α	YA
L	L	L
L	н	н
Н	Х	Z
Inpu	ts	Output
Enable B	В	YB
Н	L	L
н	н	н
L	Х	Z



MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit
VCC	DC Supply Voltage (Referenced to GND)	– 0.5 to + 7.0	V
Vin	DC Input Voltage (Referenced to GND)	– 1.5 to V _{CC} + 1.5	V
Vout	DC Output Voltage (Referenced to GND)	-0.5 to V _{CC} + 0.5	V
l _{in}	DC Input Current, per Pin	± 20	mA
l _{out}	DC Output Current, per Pin	± 35	mA
ICC	DC Supply Current, V_{CC} and GND Pins	± 75	mA
PD	Power Dissipation in Still Air, Plastic or Ceramic DIP† SOIC Package†	750 500	mW
T _{stg}	Storage Temperature	– 65 to + 150	°C
т	Lead Temperature, 1 mm from Case for 10 Seconds (Plastic DIP or SOIC Package) (Ceramic DIP)	260 300	°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range GND $\leq (V_{in} \text{ or } V_{out}) \leq V_{CC}$. Unused inputs must always be tied to an appropriate logic voltage

level (e.g., either GND or V_{CC}). Unused outputs must be left open.

* Maximum Ratings are those values beyond which damage to the device may occur.

Functional operation should be restricted to the Recommended Operating Conditions.

†Derating — Plastic DIP: – 10 mW/°C from 65° to 125°C

Ceramic DIP: - 10 mW/°C from 100° to 125°C

SOIC Package: - 7 mW/°C from 65° to 125°C

For high frequency or heavy load considerations, see Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
VCC	DC Supply Voltage (Referenced to GND)	4.5	5.5	V
V _{in} , V _{out}	DC Input Voltage, Output Voltage (Referenced to GND)	0	VCC	V
Т _А	Operating Temperature, All Package Types	- 55	+ 125	°C
t _r , t _f	Input Rise and Fall Time (Figure 1)	0	500	ns

DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

				Guaranteed Limit			
Symbol	Parameter	Test Conditions	VCC V	– 55 to 25°C	≤ 85°C	≤ 125°C	Unit
VIH	Minimum High–Level Input Voltage	$V_{out} = 0.1 \text{ V or } V_{CC} - 0.1 \text{ V}$ $ I_{out} \le 20 \ \mu\text{A}$	4.5 5.5	2 2	2 2	2 2	V
VIL	Maximum Low–Level Input Voltage	$V_{out} = 0.1 \text{ V or } V_{CC} - 0.1 \text{ V}$ $ I_{out} \le 20 \ \mu\text{A}$	4.5 5.5	0.8 0.8	0.8 0.8	0 8 0.8	V
VOH	Minimum High–Level Output Voltage	V _{in} = V _{IH} or V _{IL} I _{out} ≤ 20 μA	4.5 5.5	4.4 5.4	4.4 5.4	4.4 5.4	V
		$V_{in} = V_{IH} \text{ or } V_{IL}$ $ I_{out} \le 6 \text{ mA}$	4.5	3.98	3.84	3.7	
VOL	Maximum Low–Level Output Voltage	$V_{in} = V_{IH} \text{ or } V_{IL}$ $ I_{out} \le 20 \ \mu A$	4.5 5.5	0.1 0.1	0.1 0.1	0.1 0.1	V
		$V_{in} = V_{IH} \text{ or } V_{IL}$ $ I_{out} \le 6 \text{ mA}$	4.5	0.26	0.33	0.4	
l _{in}	Maximum Input Leakage Current	V _{in} = V _{CC} or GND	5.5	± 0.1	± 1.0	± 1.0	μΑ
IOZ	Maximum Three–State Leakage Current	Output in High–Impedance State V _{in} = V _{IL} or V _{IH} V _{out} = V _{CC} or GND	5.5	± 0.5	± 5.0	± 10	μΑ
ICC	Maximum Quiescent Supply Current (per Package)	V _{in} = V _{CC} or GND I _{out} = 0 μA	5.5	4	40	160	μA

MC54/74HCT241A

ΔICC	Additional Quiescent Supply Current	$V_{in} = 2.4$ V, Any One Input $V_{in} = V_{CC}$ or GND, Other Inputs		≥ -55°C	25°C to 125°C	
	ouncil	$I_{out} = 0 \mu A$	5.5	2.9	2.4	mA

NOTES:

Information on typical parametric values along with frequency or heavy load considerations can be found in Chapter 2 of the Motorola High– Speed CMOS Data Book (DL129/D).
 Total Supply Current = I_{CC} + ΣΔI_{CC}.

AC ELECTRICAL CHARACTERISTICS (V_{CC} = 5.0 V \pm 10%, C_L = 50 pF, Input t_f = t_f = 6 ns)

		Guaranteed Limit			
Symbol	Parameter	– 55 to 25°C	≤ 85°C	≤ 125°C	Unit
^t PLH [,] ^t PHL	Maximum Propagation Delay, A to YA or B to YB (Figures 1 and 3)	23	29	35	ns
^t PLZ [,] ^t PHZ	Maximum Propagation Delay, Output Enable to YA or YB (Figures 2 and 4)	30	38	45	ns
t _{PZL} , t _{PZH}	Maximum Propagation Delay, Output Enable to YA or YB (Figures 2 and 4)	26	33	39	ns
t _{TLH} , t _{THL}	Maximum Output Transition Time, Any Output (Figures 1 and 3)	12	15	18	ns
C _{in}	Maximum Input Capacitance	10	10	10	pF
Cout	Maximum Three–State Output Capacitance (Output in High–Impedance State)	15	15	15	pF

NOTE: For propagation delays with loads other than 50 pF, and information on typical parametric values, see Chapter 2 of the Motorola High– Speed CMOS Data Book (DL129/D).

		Typical @ 25°C, V _{CC} = 5.0 V	
C _{PD}	Power Dissipation Capacitance (Per Enabled Output)*	55	pF

* Used to determine the no–load dynamic power consumption: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$. For load considerations, see Chapter 2 of the Motorola High–Speed CMOS Data Book (DL129/D).

SWITCHING WAVEFORMS









Figure 1.



* Includes all probe and jig capacitance





Figure 4. Test Circuit



LOGIC DETAIL

OUTLINE DIMENSIONS



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